

WHAT IS CLAIMED IS:

1. An active matrix display device, comprising:
a first substrate;
a second substrate;
a third substrate;
active elements formed on the first substrate;
wiring lines formed on the second substrate;
electro-optical elements formed on the third substrate; and
an element chip having at least one active element peeled off from the first substrate and transferred onto at least one of the second substrate and the third substrate, the second substrate adhering to the third substrate, the active elements being electrically connected to the wiring lines on one surface of the element chip facing the second substrate, and the active elements being electrically connected to the electro-optical elements on another surface of the element chip facing the third substrate.
2. The active matrix display device according to Claim 1,
the electrical connection being performed by a conductive material.
3. The active matrix display device according to Claim 2,
the conductive material being disposed in a position corresponding to the periphery of the element chip between the element chip and the second or third substrate, and the active elements being electrically connected to the electro-optical elements.
4. The active matrix display device according to Claim 2,
an opening being formed in the element chip, the conductive material being disposed in a position corresponding to the opening between the element chip and at least one of the second substrate and the third substrate, and the active elements being electrically connected to the electro-optical elements.
5. A thin film transistor display device, comprising:
the active matrix display device according to Claim 1, the active elements being thin film transistors.